TOSHIBA Bipolar Linear Integrated Circuit Silicon Monolithic

TA2099N,TA2099F

AM/FM IF + FM Stereo Detector (for Digital Tuning System)

TA2099N and TA2099F are the AM/FM IF + FM Stereo Detector IC, which is designed for DTS Radios.

This is included many functions and this can be used for Digital Tuning System with IF Counter.

Features

 Suitable for combination with Digital Tuning System which has IF Counter.

AM/FM IF Count Output for IF Counter

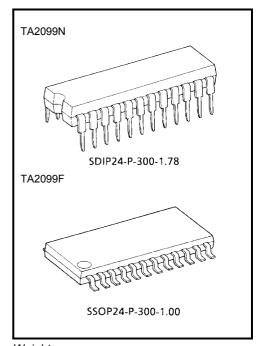
Built-in mute Circuit for IF Count Output

Built-in mute Circuit for Audio Output

FM IF Count Output Sensitivity is adjustable by external resistance

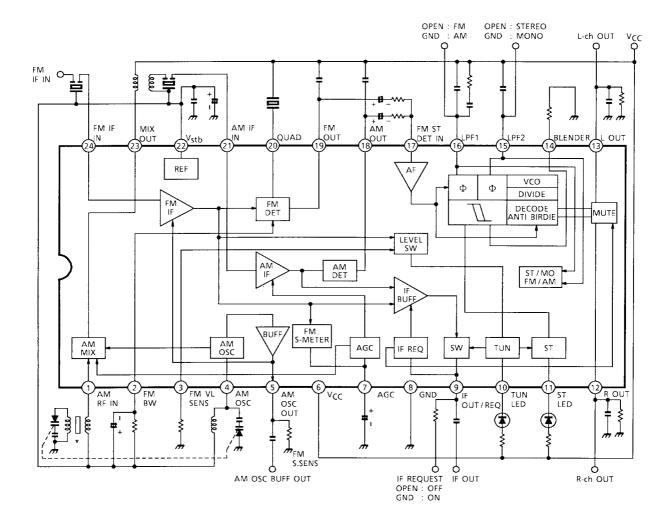
- Built-in FM Narrow Detector Circuit

 Band Width is adjustable by external resistance
- FM LED ON sensitivity is adjustable by external resistance
- Built-in Resonance Circuit for FM Stereo Detector VCO
- Built-in FM Blender Control Circuit
- Built-in Anti-birdie Circuit
- Built-in AM Local OSC Buffer Output Circuit
- Operating Supply Voltage Range: VCC = 4.0~9 V (Ta = 25°C)



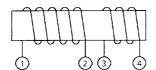
Weight: SDIP24-P-300-1.78: 1.2 g (typ.) SSOP24-P-300-1.00: 0.31 g (typ.)

Block Diagram



*: The Toshiba evaluation board uses the bar antenna shown below.

Use	f	L	Qo	Number of Windings 1-2 3-4		Winding Thickness (mm)	Note
MW ANT	796 kHz	220 µH	150~220	20 59 17		3/0.07 µATC	Mitsumi L-3107



Terminal Explanation (Terminal voltage shows the typical value at Ta = 25°C, V_{CC} = 5V, SW₃: OFF, SW₉: GND and non-signal test circuit)

Pin No.	Characteristics	Internal Circuit	DC Vol	tage (V)
1 111110.	Ondracteristics	mema orean	FM	AM
1	AM RF IN	AM MIX OUT AM OSC AGC AGC	2.0	2.0
2	FM BW • FM band width adjust terminal	V _{CC} FM DET CIRCUIT V _{stb}	2.0	2.0
3	FM VL SENS • FM LED ON sensitivity adjust terminal	VCC TUN LED	0.1	0.1
4	AM OSC	V _{stb}	2.0	2.0

Pin No.	Characteristics	Internal Circuit	DC Vol	tage (V)
i iii ivo.	Granacienstics	memai ondat	FM	AM
5	AM OSC OUT/FM S.SENS • AM OSC Buff Output Terminal • FFM IF Count Output Sensitivity Adjust Terminal	VCC Vstb VStb AM OSC S FM S.SENS CONTROL TM	1.3	1.3
6	Vcc	<u> </u>	5.0	5.0
7	AGC (FM S-METER)	AM DET OUT VCC AM DET U N S FM FM S-METER CIRCUIT	0.2	1.3
8	GND	_	0	0
9	IF OUT/REQ ■ IF Count Output Terminal ■ IF Count Output/FM ST DET Mute Circuit Control Terminal SW ₃ : GND → ON SW ₃ : Open → OFF	V _{Stb} V _{Stb} AM IF	_	_
10	TUN LED	10	_	_

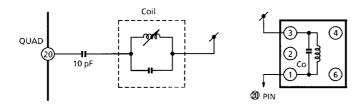
Pin No.	Characteristics	Internal Circuit	DC Vol	tage (V)
1 11110.	Characteristics	mornal Orban	FM	AM
11	ST LED	Vcc vco	_	_
12	R OUT		1.2	1.2
13	L OUT	12/13	1.2	1.2
14	BLENDER • FM Blender Control Adjust Terminal	Vcc Vcc	0.3	0.3
15	LPF2 • LPF Terminal for Synchronous Detector • VCO Stop Terminal V ₁₅ = GND → VCO Stop (Monaural) V ₁₅ = Open → VCO Run (Stereo)	DC AMP	3.5	1.4
16	LPF1 • LPF Terminal for Phase Detector • Bias Terminal for AM/FM Switch Circuit V ₁₆ = GND → AM V ₁₆ = Open → FM	IS AM/FM	3.5	0
17	FM ST DET IN	14.1κΩ	1.2	1.2

Pin No.	Characteristics	Internal Circuit	DC Vol	tage (V)
1 11110.	Ondraotenotios	mema oroan	FM	AM
18	AM DET OUT	V _{CC} C 4.9kΩ CO AGC M M M	0	1.3
19	FM DET OUT	VCC 4.9 kΩ FM NARROW DETECTOR	1.4	2.0
20	QUAD		1.8	2.3
21	AM IF IN	V _{stb} V _{CC} Graph (2)	2.0	2.0
22	V_{stb}	VCC VCC	2.0	2.0

Pin No.	Characteristics	Internal Circuit	DC Vol	tage (V)
FIII NO.	Characteristics	internal Circuit	FM	AM
23	AM MIX OUT	AM OSC AM RF N AGC AGC AGC	5.0	5.0
24	FM IF IN	Vcc Vstb	2.0	2.0

Operations in Detail

1. Application circuit when using a coil demodulator

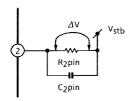


Coil data

	f	C _o	0	Number of Wire Turns			Wire	Domarko	
	(Hz)	(pF)	Qo	1-2	-2 2-3 1-3 (mmφ)		(mmφ)	Remarks	
FM DET	10.7 M	51	45			30	0.08 φ 2 UEW	TOKO Co., Ltd. 600BEAS-10018Z	

2. Center meter adjustment

It can be switch Δ V, pin voltages between 2-pin and 22-pin (V_{stb}) for narrow band detection or both side of R₂ pin voltages, to 0 V to adjust a coil. This adjustment made possible to set the voltage to center voltage and the midpoint of lighting LED band to the frequency (10.7 MHz).



Assembled C2 pin and R2 pin compose HPF.

$$f_c = \frac{1}{2\pi RC}$$

Select R₂ pin in accordance with specifications for narrow band detection and set C₂ pin by following that of resistance. Please take these into account.

3. Function switching

(1) $FM \rightarrow AM$ switching

Pin 16: Connect the LPF1 pin to GND.

(Adjust using external parts so that the voltage does not exceed 0.6 V.)

(2) SEREO \rightarrow MONO switching (Note 1)

Pin 15: Connect the LPF2 pin to GND.

(Adjust using external parts so that the voltage does not exceed 0.6 V.)

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Note 1: When STEREO/FM is selected, the multiplex VCO frequency changes due to 0.1 µA flow.

(3) IF OUT \rightarrow ON switching

Pin 9: When the voltage on the IF OUT/REQ pin is set to 1.3 V or below (V_{stb} (2 V) – Vbe (0.7 V)) and about 500 μA current flows, switch to ON. Toshiba recommends a load of 2.2 k Ω .

4. External change function

(1) Narrowband detector: When the FM IF input signal is off-center, 10.7 MHz, by a few kHz, the detector turns TUN-LED OFF.

Pin 2: Adjusts bandwidth using the resistor of the FM BW pin. In combination with the C₂ pin, the R₂ pin configures an HPF. The smaller the pin 2 capacitance, the higher the HPF cutoff. Note that when low-frequency sound is input, although tuning is maintained, the detector may turn TUN-LED OFF.

(2) LED ON sensitivity adjustment

Pin 3: Uses the FM VL SENS pin resistor value to change the ON sensitivity of TUN-LED.

(3) IF counter output sensitivity adjustment (Note 2)

Pin 5: Uses the FM S. SENS pin resistor value to change the sensitivity of the IF count output at IF count ON.

Note 2: For the LED on sensitivity, (2) and (3) are linked.

At IF count ON (connect resistor for pin 9 to GND), the internal current depending on the pin 5 resistor value changes the IF amp gain, the S meter startup, and the IF input level (sensitivity).

The LED ON sensitivity turns the LED ON by comparing the voltage which depends on the pin 3 resistor value with the S meter voltage. The change in S meter startup (sensitivity) at IF count ON causes the LED ON sensitivity set at IF count OFF to change. Therefore, confirm the LED ON sensitivity according to the seek operation specification.

(4) Blender control

Pin 14: Changes the MPX L and R signal separation according to the input level set by the resistance.

5. Others

(1) $V_{\rm stb}$

Pin 22: Set to 2 V internally.

(2) QUAD

Pin 20: Supports both a ceramic discriminator and a detector coil for QUAD. See 1, in Description of Operation.

Note that when a detector coil is used, S/N and the skew ratio deteriorates.

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(3) L, R output

Pins 12, 13: L-OUT and R-OUT pins are used for current output. The external resistor is set to output impedance. This is specified when the load is $5.1 \text{ k}\Omega$ and $0.01 \text{ \mu}F$.

(4) AGC

Pin 7: Also used as the FM S meter.

Maximum Ratings (Ta = 25°C)

Characteris	tics	Symbol	Rating	Unit
Supply voltage		V _{CC}	10	V
LED current		I _{LED}	10	mA
LED voltage		V _{LED}	14	V
Power dissipation	TA2099N	P _D (Note 3)	1200	mW
Power dissipation	TA2099F	PD (Note 3)	400	IIIVV
Operating temperature		T _{opr}	-25~75	°C
Storage temperature		T _{stg}	-55~150	°C

Note 3: Derated above 25°C in the proportion of 9.6 mW/°C for TA2099N and of 3.2 mW/°C for TA2099F.

Electrical Characteristics

(unless otherwise specified,

Ta = 25°C, V_{CC1} = 5 V, SW_3 = OFF, FM IF: f = 10.7 MHz, Δf = ± 22.5 kHz, f_m = 1 kHz,

AM: f = 1 MHz, MOD = 30%, f_m = 1 kHz,

FM ST DET: f_m = 1 kHz)

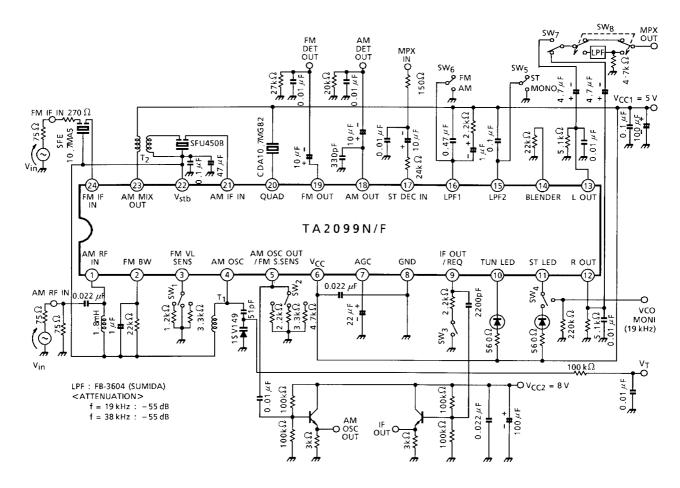
	Characteristics	Symbol	Test Circuit	Test Cond	dition	Min	Тур.	Max	Unit	
Sunn	ly current	I _{CC} (FM)	1	FM Mode, V _{in} = 0		_	17	23	mA	
Supp	ly current	I _{CC} (AM)	1	AM Mode, V _{in} = 0		_	14	20	IIIA	
	Input limiting voltage	V _{in (lim)}	1	-3dB limiting point		37	41	45	dBµV EMF	
	Recovered output voltage	ecovered output voltage V _{OD (FM)} 1 V _{in} = 80dBµV EMF		75	100	125	mVrms			
	Signal to noise ratio	S/N (FM)	1	V _{in} = 80dBµV EMF		_	71	_	dB	
	Total harmonic distortion	THD (FM)	1	V _{in} = 80dBµV EMF		_	0.1	_	%	
	AM rejection ratio	AMR	1	V _{in} = 80dBµV EMF		_	55	_	dB	
FM IF					SW ₁ : 0 Ω	_	41	_		
I IF	LED on sensitivity	V _{L (FM)}	1	I _L = 1 mA	SW ₁ : 1.2 kΩ	41	46	51	dBµV EMF	
					SW ₁ : 3.3 kΩ	_	54	_		
	IF count output voltage	V _{IF (FM)}	1	SW ₃ : ON, V _{in} = 80dBµV EMF		240	290	_	mV _{p-p}	
	IF count output sensitivity				SW ₂ : 2.2 kΩ	_	58	_	dBµV EMF	
		IF _{sens} (FM)	1	SW ₃ : ON	SW ₂ : 3.3 kΩ	47	53	59		
					SW ₂ : 4.7 kΩ	_	50	_		
	Gain	G _V	1	V _{in} = 23dBµV EMF		28	50	82	mVrms	
	Recovered output voltage	V _{OD (AM)}	1	V _{in} = 60dBµV EMF		70	100	130	mVrms	
	Signal to noise ratio	S/N (AM)	1	V _{in} = 60dBμV EMF		_	45	_	dB	
	Total harmonic distortion	THD (AM)	1	V _{in} = 60dBµV EMF		_	0.5	_	%	
AM	LED on sensitivity	V _{L (AM)}	1	I _L = 1 mA		21	26	31	dBµV EMF	
	Local OSC buffer output	\/ (ABA)	1	f _{OSC} = 1.45 MHz		350	480	_		
	voltage	V _{OSC} (AM)	2	f _{OSC} = 27 MHz		_	480	_	mV _{p-p}	
	IF count output voltage	V _{IF} (AM)	1	SW ₃ : ON, V _{in} = 60d	BµV EMF	250	370	_	mV _{p-p}	
	IF count output sensitivity	IF _{sens} (AM)	1	SW ₃ : ON		_	26	_	dBµV EMF	

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	Characteristics		Symbol	Test Circuit	Test Cond	dition	Min	Тур.	Max	Unit
	Max composite input voltage		V _{in} (MAX) (STEREO)	1	L + R = 90%, P = 10% THD = 3%, SW ₈ → LPF: ON		_	700	_	mVrms
					L + R = 180 mVrms	f _m = 100 Hz	_	45	_	
	Separation		Sep	1	P = 20 mVrms	f _m = 1 kHz	35	45	_	dB
					SW ₈ → LPF: ON	f _m = 10 kHz	_	45	_	
			THD (MONO)	1	V _{in} = 200 mVrms (M	_	0.05	_		
FM			THD (STEREO)	1	L + R = 180 mVrms, P = 20 mVrms SW ₈ \rightarrow LPF: ON	_	0.05	_	%	
ST DET	Voltage gain		G _V (ST)	1	V _{in} = 200 mVrms (MONO)		-2	-0.6	1	dB
	Channel balance)	C.B.	1	V _{in} = 200 mVrms (M	IONO)	-1.5	0	1.5	dB
	Stereo LED	ON	V _L (ON)	1	Pilot input		_	10	16	m\/rma
	sensitivity	OFF	V _L (OFF)	1	Filot iriput		4	8	_	mVrms
	Stereo LED hyst	eresis	V _H	1	to LED turn-off form	LED turn-on	_	2	_	mVrms
	Capture range		C.R	1	P = 20 mVrms		_	±4.5	_	%
	Signal to noise ratio		S/N (ST)	1	V _{in} = 200 mVrms (MONO)		_	80	_	dB
	VCO frequency		fvco/12	1	Specified when SW ₂ VCO/12	4 = ON, MPX	-300	19 k	+300	Hz

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Test Circuit 1



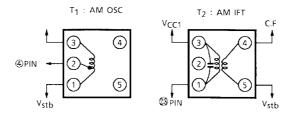
Coil Data (Test Circuit 1)

Coil No.	f	L	Co	Q_0	Turn			Wire	Ref.	
Coll No.	1	(µH)	(pF)	3	1-2	2-3	1-3	4-6	(mmφ)	(Coil No.)
T ₁ AM OSC	796 kHz	120	I	120	13	56	_	_	0.07 UEW	S: 2157-2239-779 T: A7BRS-12552Y M: MJ-3273-3
T ₂ AM IFT	455 kHz	_	330	100	_	_	110	6	0.08 UEW	S: 4140-1289-311 T: 7MES-11368N M: MJ-3337-1

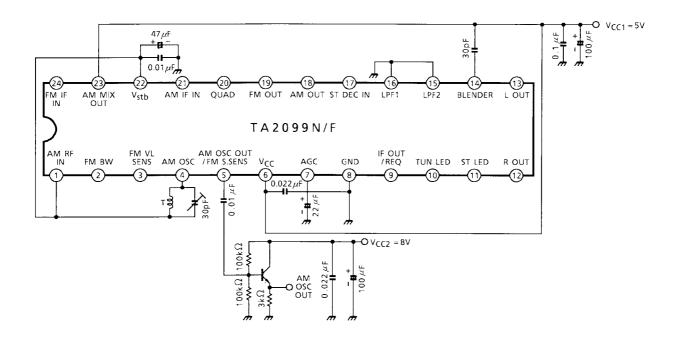
S: SUMIDA ELECTRIC Co., Ltd.

T: TOKO Co., Ltd.

M: MITSUMI ELECTRIC Co., Ltd.



Test Circuit 2

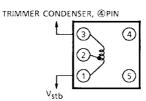


Coil Data (Test Circuit 2)

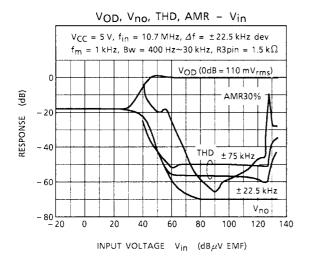
Coil No.	f	L	Co	0.		Τι	ırn		Wire	Ref.	
Coll No.	ı	(µH)	(pF)	ß	1-2	2-3	1-3	4-6	(mmφ)	(Coil No.)	
T AM OSC	7.96 MHz	1.4	1	84	1	6	7	1	0.08 UEW	T: 7PL-1344Y	

T: TOKO Co., Ltd.

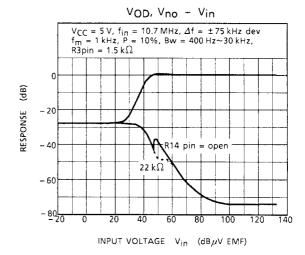
T : AM OSC



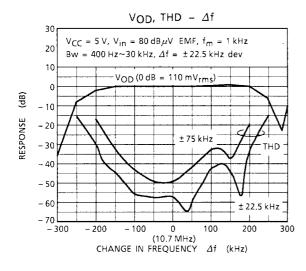
FM MONO



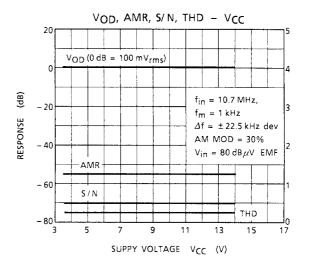
FM ST (Main)



FM



FΜ



V_L ON - R₃ pin

80

70

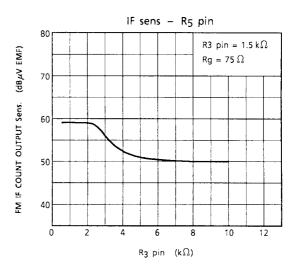
60

50

40

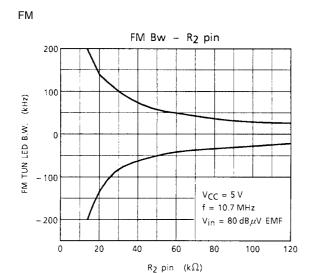
0 2 4 6 8 10 12

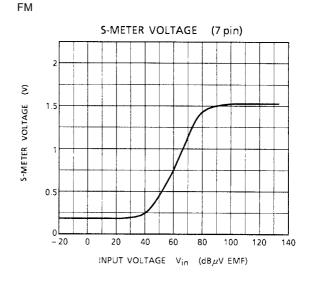
R₃ pin $(k\Omega)$

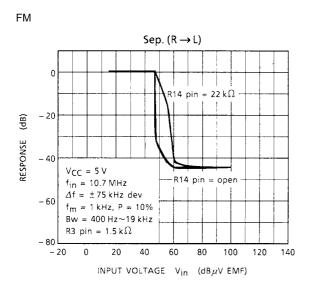


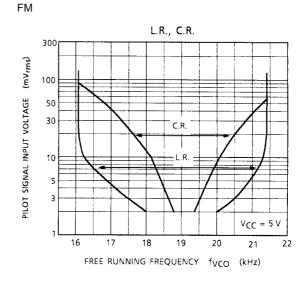
TOTAL HARMONIC DISTORTION THD (%)

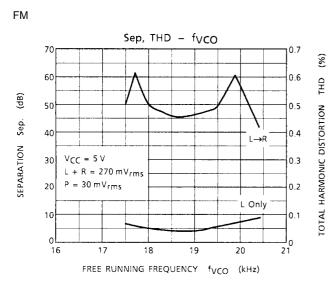
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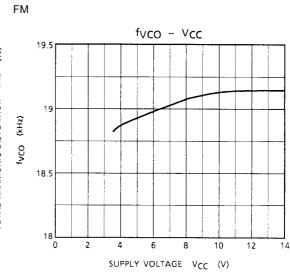


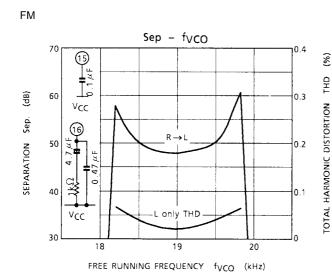


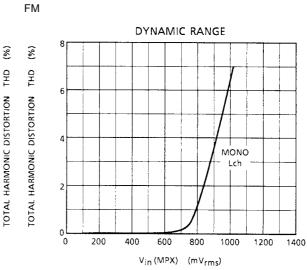




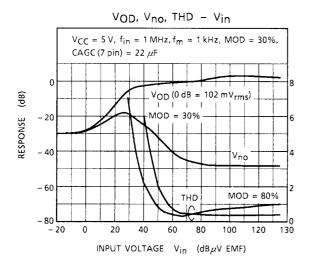




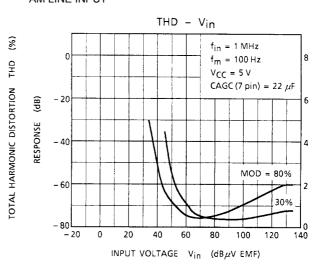




AM LINE INPUT



AM LINE INPUT

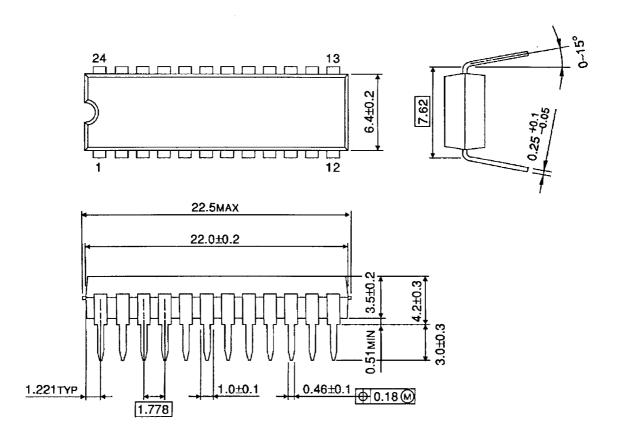


TOTAL HARMONIC DISTORTION THD (%)

Unit: mm

Package Dimensions

SDIP24-P-300-1.78

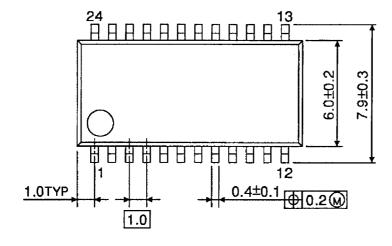


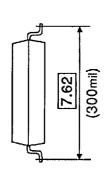
Weight: 1.2 g (typ.)

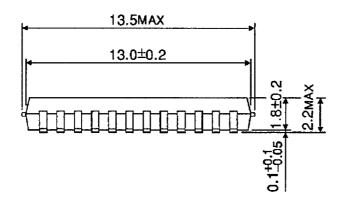
Unit: mm

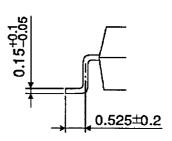
Package Dimensions

SSOP24-P-300-1.00









Weight: 0.31 g (typ.)

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000707EBA

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